

Lecture 3:

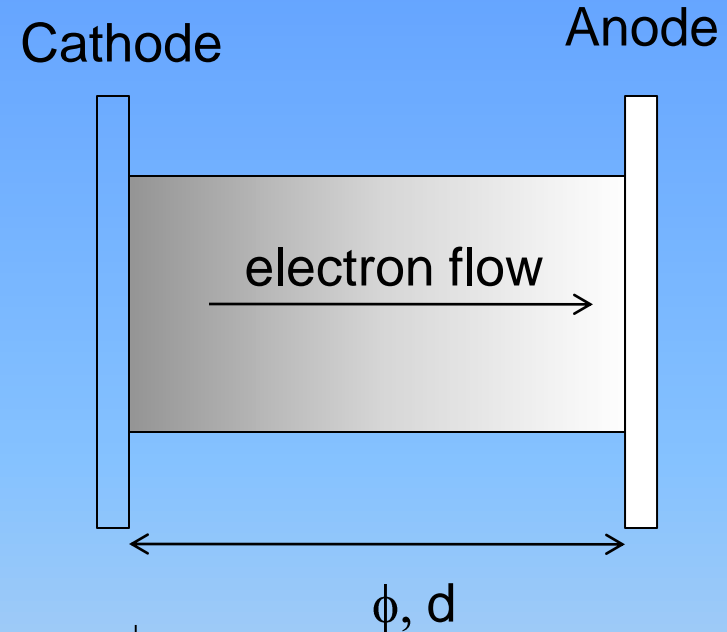
Space Charge Limited Emission

- The object of this lecture is to define the concept of space charge limited emission. This is done by deriving the Child-Langmuir law for a DC diode and the space charge limit for the short pulse of a photocathode gun. The differences of these two cases are discussed.
- The space charge limit is applied to the observed operation of RF photocathode guns.
- The connection between the space charge limit and the lowest achievable emittance is derived and discussed.

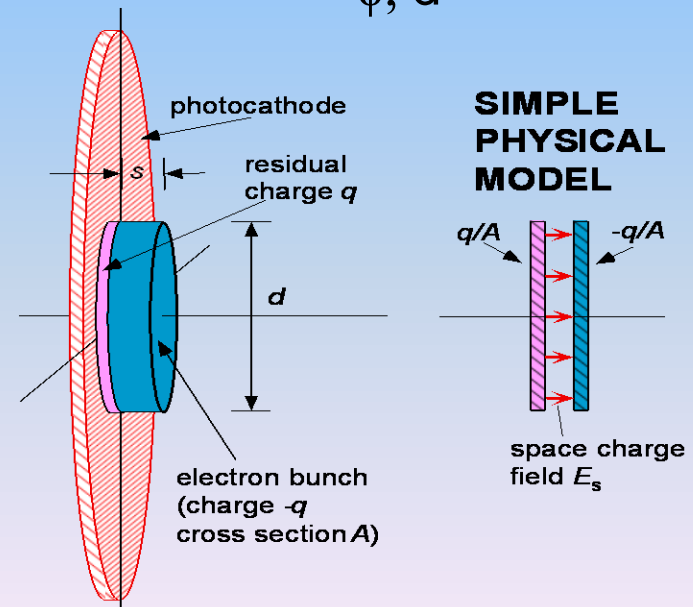


Difference between SCL for DC diode and short pulse photo-emission

**Space Charge Field
Across a Diode,
Child-Langmuir law:**



**Space Charge Field from a
Short Electron Bunch,
Laser-driven Photocathodes:**



Space Charge in a Diode

$$\frac{1}{2} m v^2 = eV \quad \text{Conservation of energy}$$

$$\nabla^2 V = \frac{\rho}{\epsilon_0} \quad \text{Poisson's Egn.}$$

$$\vec{E} = -\nabla V, \quad \nabla \cdot \vec{E} = \frac{\rho}{\epsilon_0}$$

a steady-state,
 → Assume a one-dimensional flow of the current,

$$\frac{d^2 V}{dx^2} = \frac{\rho_a}{\epsilon_0} \quad \text{and} \quad E = -\frac{dV}{dx}$$

The current surface density, amps/m², is

$$I_a = \rho_a v; \quad v = \sqrt{\frac{2eV}{m}}$$

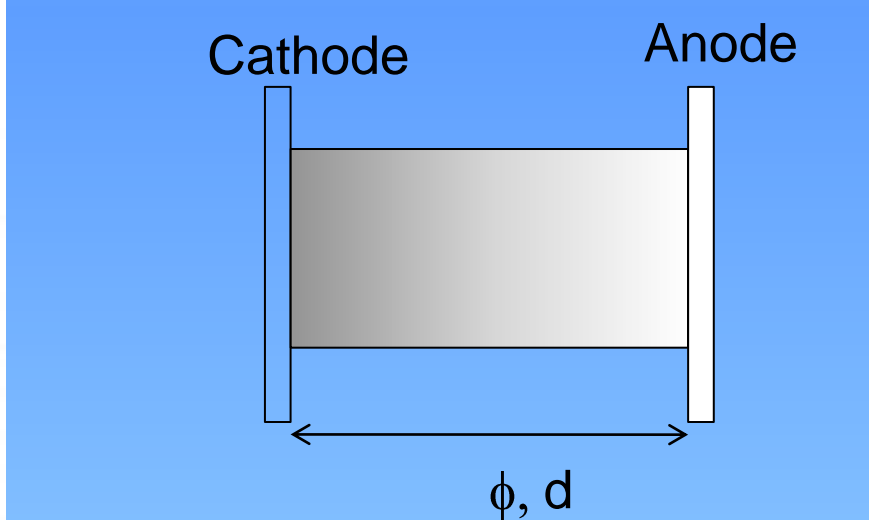
$$\rho_a = \frac{I_a}{v} = I_a \sqrt{\frac{m}{2eV}}$$

$$\frac{d^2 V}{dx^2} = \frac{I_a}{\epsilon_0} \sqrt{\frac{m}{2eV}}$$

Realize/Common Trick:

$$d\left(\frac{dV}{dx}\right)^2 = 2 \frac{dV}{dx} \frac{d^2 V}{dx^2} dx = 2 \frac{d^2 V}{dx^2} dV$$

$$\left(\frac{dV}{dx}\right)^2 = E^2 = 2 \frac{I_a}{\epsilon_0 \sqrt{2\frac{e}{m}}} \int_0^V \frac{dV}{V^{1/2}} = \frac{4I_a}{\epsilon_0 \sqrt{2\frac{e}{m}}} V^{1/2}$$



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$$\frac{dV}{V^{1/2}} = \left[\frac{4I_a}{\epsilon_0 \sqrt{2\frac{e}{m}}} \right]^{1/2} dx$$

$$\frac{4}{3} V^{3/2} = \left[\frac{4I_a}{\epsilon_0 \sqrt{2\frac{e}{m}}} \right]^{1/2} x$$

Solve for the steady-state current to get Child's Law, (Child-Langmuir law)

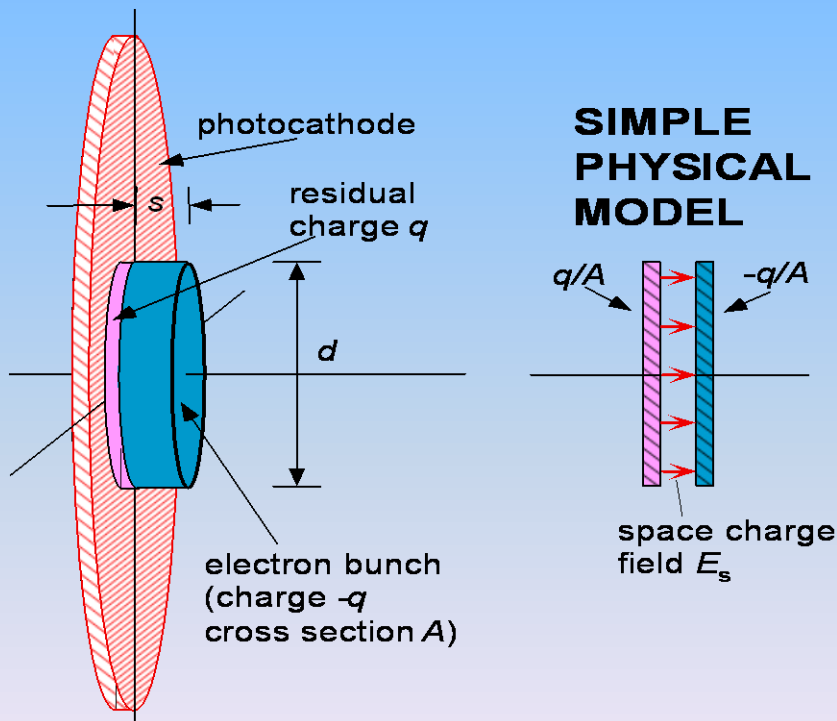
$$I_a = \frac{4}{9} \epsilon_0 \sqrt{2\frac{e}{m}} \frac{V^{3/2}}{d^2} = J \text{ current surface density}$$

d is the gap length of the diode.

$$J = 2.33 \times 10^{-6} \frac{V^{3/2}}{d^2} \text{ [A/m}^2\text{]}$$

with V in volts and d in meters.

Electron emission is strongly affected by self-fields produced by the electron bunch itself. Immediately at the cathode surface, the electrons experience their own image charge which for metal cathodes produces a field which opposes the applied electric field. The magnitude of this field is easily estimated by considering the electron bunch as a very thin charge sheet very close to the cathode surface. Then the space charge field is similar to that between the plates of a capacitor as shown



Space charge electric field:

$$E_{sc} = \frac{Q}{A\epsilon_0} = \frac{\sigma}{\epsilon_0}$$

SCL occurs when
space charge field = applied field

$$E_{sc} = \frac{Q}{A\epsilon_0} = \frac{\sigma}{\epsilon_0} = E_{applied}$$

Limiting surface charge density:

$$\sigma_{sc-limit} = \epsilon_0 E_{applied}$$



Space charge limited (SCL) emission in a RF gun

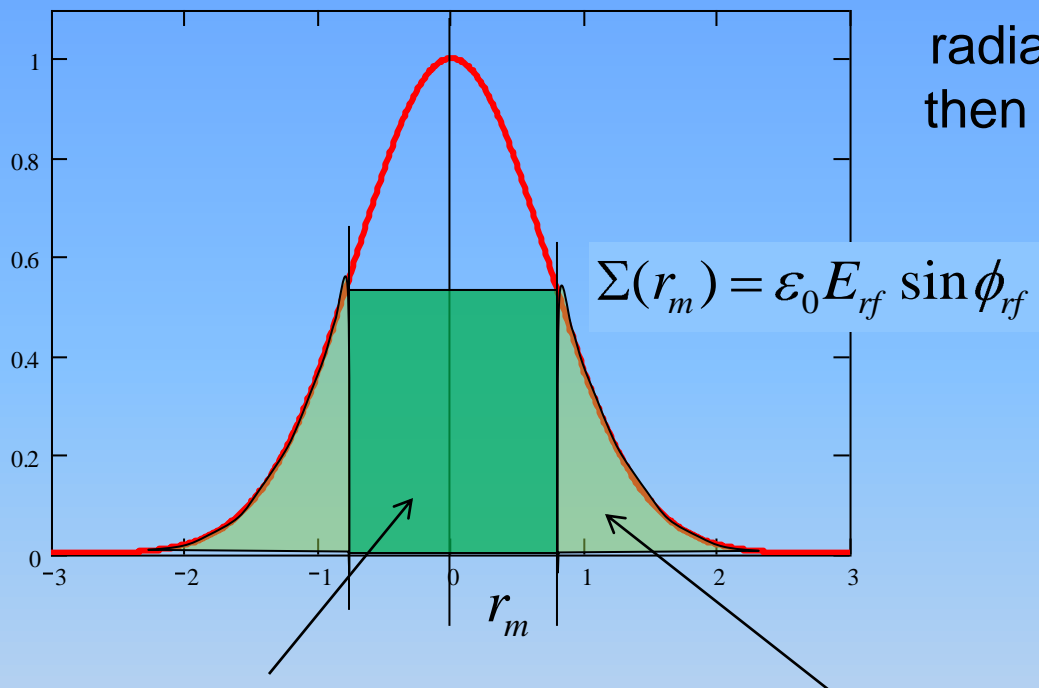
Assume a Gaussian radial distribution on the cathode, then the surface charge density is

$$\Sigma(r) = \frac{Q_{bunch}}{2\pi\sigma_r^2} e^{-\frac{r^2}{2\sigma_r^2}}$$

$$Q_{bunch} = \frac{eE_{laser}}{\hbar\omega} QE$$

SCL occurs when

$$\Sigma(r_m) = \varepsilon_0 E_{rf} \sin\phi_{rf}$$



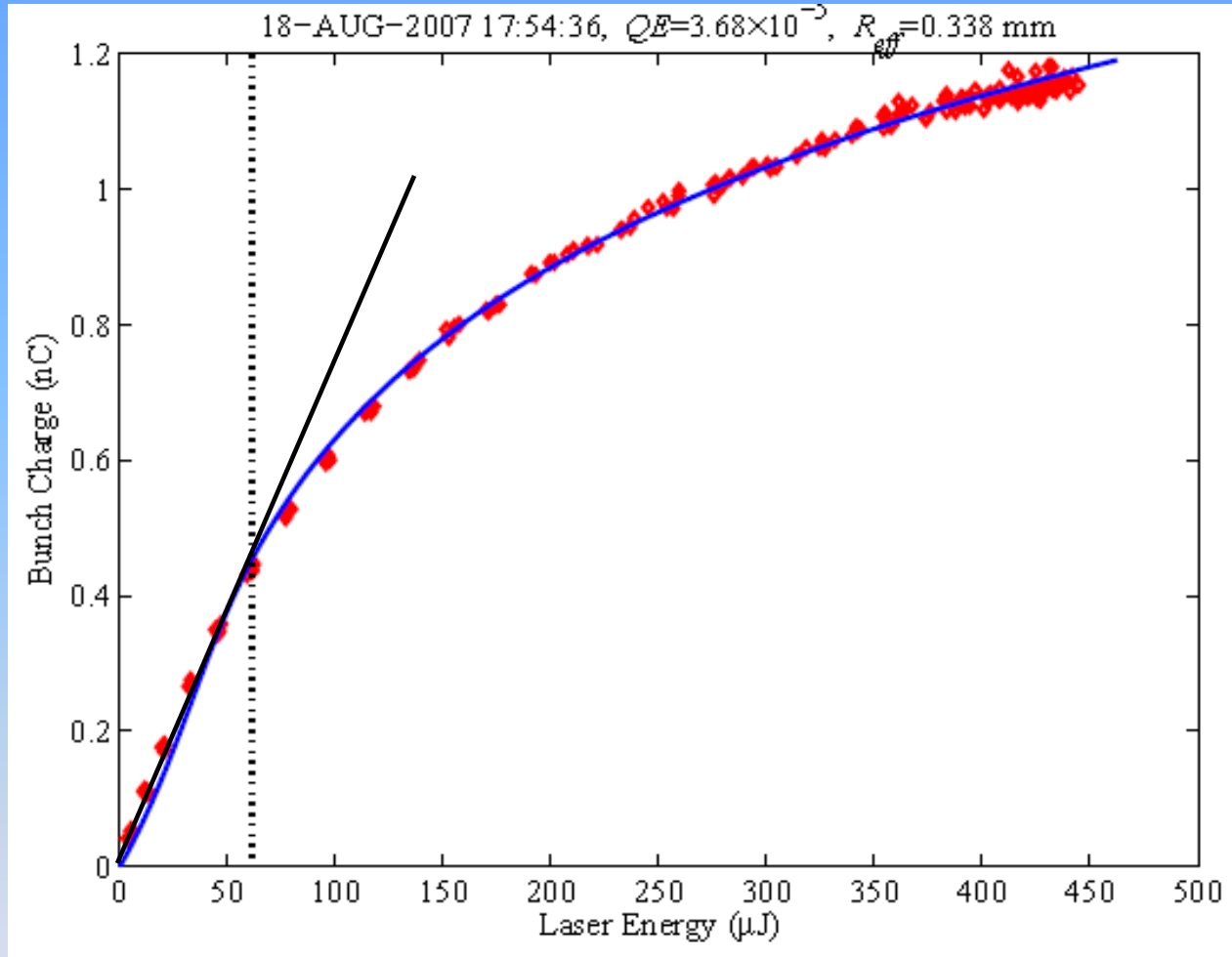
$$Q_{core} = \pi r_m^2 \varepsilon_0 E_{rf} \sin\phi_{rf}$$

$$Q_{tail} = 2\pi \int_{r_m}^{\infty} \Sigma(r) r dr = Q_{bunch} e^{-\frac{r_m^2}{2\sigma_r^2}}$$

$$Q_{emitted} = Q_{core} + Q_{tail} = \pi r_m^2 \varepsilon_0 E_{rf} \sin\phi_{rf} + QE \frac{eE_{laser}}{\hbar\omega} e^{-\frac{r_m^2}{2\sigma_r^2}}$$



Theory is used at LCLS to obtain QE and effective emission size



The measured bunch charge vs. laser energy fit with an analysis for the QE and the space charge limit. The QE in this case was 3.7×10^{-5} and the effective transverse radius is 0.34 mm rms.



SCL for Different QE's

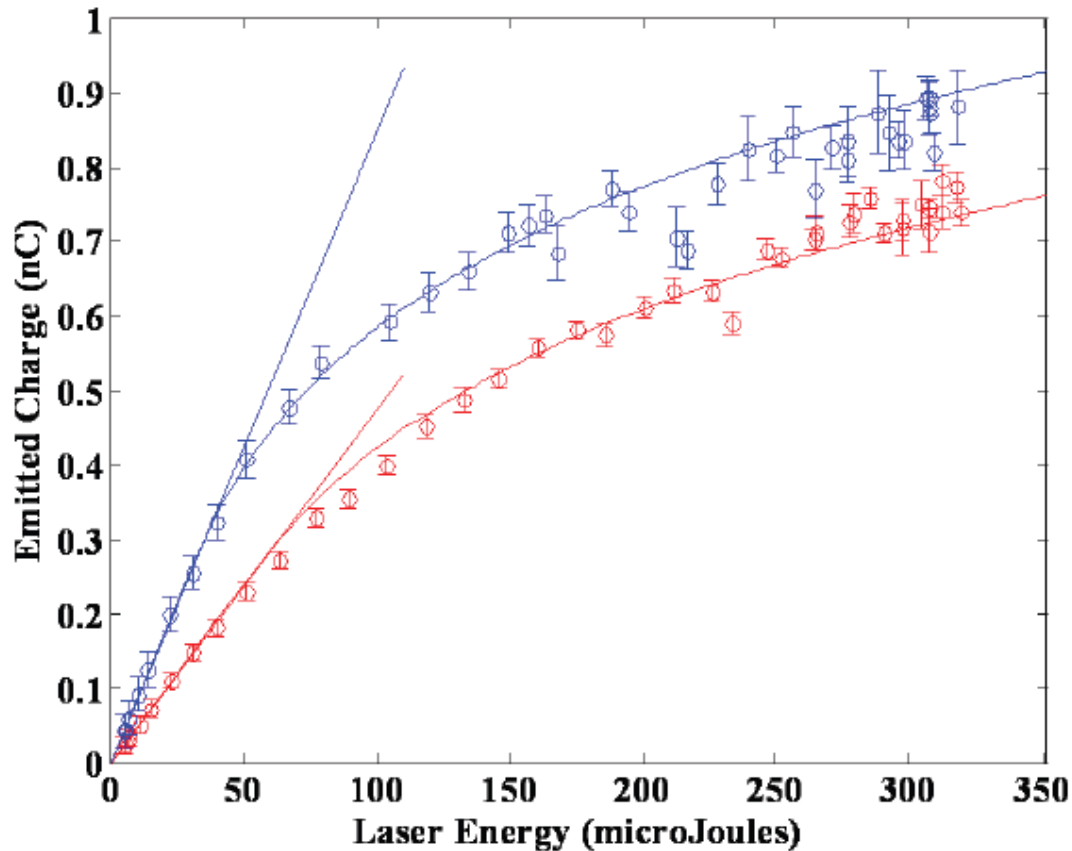


FIGURE 22. Measurements of the charge vs. the laser energy for the LCLS-gun operating at a peak cathode field of 115 MV/m. The data were taken with the same beam size (1.2 mm diameter) but for different QE.



13. THE ENVELOPE EQUATION AND BEAM PERVEANCE

The envelope equation without external focusing is,

$$(66) \quad r_m'' = \frac{\epsilon^2}{r_m^3} + \frac{K}{r_m}$$

where K is the generalized perveance (Lawson, p117) and ϵ is the geometric emittance,

$$(67) \quad K_{general} = \frac{I}{I_0} \frac{2}{\beta^3 \gamma^3} = \frac{\omega_p^2 a^2}{2\beta^2 c^2}.$$

Otherwise the perveance is defined as (Reiser, Eqn. 4.28, p.197)

$$(68) \quad K = \frac{I}{4\pi\epsilon_0 V^{3/2} \left(\frac{2e}{m}\right)^{1/2}} = \frac{I}{d^2 J_{SCL}^{CL}}$$

Where the denominator is identified as the Child-Langmuir current from Eqn. 60. Therefore the perveance is defined as the beam current divided by the space charge limited current, $d^2 J_{SCL}^{CL}$.

When the beam is in radial equilibrium, $r_e'' = 0$, the geometric emittance can be related to the perveance,

$$(69) \quad \frac{\epsilon^2}{r_e^3} = \frac{K}{r_e}$$

$$(70) \quad \epsilon = r_e \sqrt{K}$$

$$(71) \quad \epsilon = r_e \sqrt{\frac{I}{V^{3/2}} \left[\frac{1}{4\pi\epsilon_0 \left(\frac{2e}{m}\right)^{1/2}} \right]} = r_e \sqrt{\frac{I}{d^2 J_{SCL}^{CL}}} = r_e \sqrt{K}$$

Thus the square root of the perveance is the space charge limited *geometric* divergence.



The Space Charge Limited Emittance: The Lowest Possible Emittance

The space charge limited emittance is found by combining the beam size for a the short bunch at the SCL with the normalized divergence derived for photo-electric emission. If we assume the beam is transversely uniform with radius a then

$$(61) \quad a = \sqrt{\frac{Q_{bunch}}{\epsilon_0 \pi E_a}}$$

Which has the root-mean-square size of

$$(62) \quad \sigma_x = \frac{a}{2} = \sqrt{\frac{Q_{bunch}}{4\pi\epsilon_0 E_a}}$$

The normalized cathode emittance is given by

$$(63) \quad \varepsilon = \beta\gamma\sigma_x\sigma_{x'}$$

And substituting the normalized divergence for photo-electric emission results in the SCL photo-electric emittance,

$$(64) \quad \varepsilon_{photo}^{SCL} = \sqrt{\frac{Q_{bunch}(\hbar\omega - \phi_{eff})}{4\pi\epsilon_0 mc^2 E_a}}$$

Here ϕ_{eff} is the effective cathode work function which includes the Schottky effect and $\hbar\omega$ is the laser photon energy. For a bunch charge of 1 nC, an applied field of 50 MV/m, a laser energy of 4.86 eV and a copper cathode ($\phi_{eff} = 4.5eV$), the space charge limited thermal emittance is

$$(65) \quad \varepsilon_{photo}^{SCL} = 0.34 \text{ microns}$$



Lecture 3 Summary

- This lecture defines the space charge limit of electron emission for cathodes and describes the difference between the Child-Langmuir law for long pulse thermionic-like emission and short pulse photoemission. Formulas for the SCL for each case are derived.
- For the photo-emission SCL the function for the emitted charge vs the drive laser energy is derived for a Gaussian laser profile which is useful for obtaining the QE from laser-limited emission and for obtaining the rms of the effective (laser+QE) emission profile.
- The perveance was related to the geometric divergence at the SCL and the ultimate emittance derived in terms of the SCL and the intrinsic cathode emittance.

[Homework problem](#)

